

FEATURES

- 0.8 inch (20.4 mm) Digit Height.
- Low current operation.
- Case mold type.
- Black face, White segment.
- RoHS compliant, Pb Free.

DESCRIPTION

The OPD-S8022LA-BW & OPD-S8023LA-BW is a 0.8 inch (20.4 mm) height single 7-segment display.

This device utilizes Super Bright Amber LED chip which are made from AlGalnP on a transparent GaAs, substrate. The display has Black face, White segment.

DEVICE

PART NO Super Bright Amber	DESCRIPTION			
OPD-S8022LA-BW	Common Anode			
OPD-S8023LA-BW	Common Cathode			

RoHS Compliance



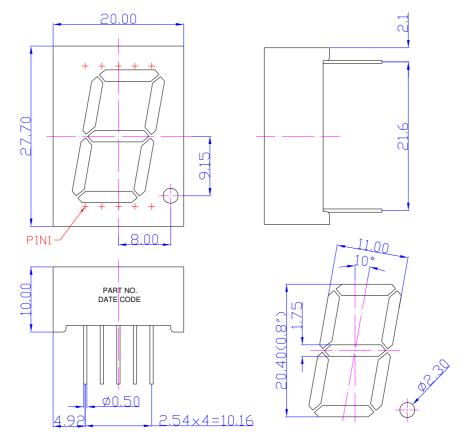
Pb free.



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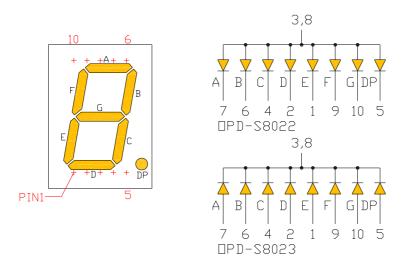


MECHANICAL DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are ± 0.25 mm unless otherwise noted.

TYPICAL INTERNAL EQUIVALENT CIRCUIT



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■ LA: SUPER BRIGHT AMBER (AlGaInP/GaAs)

ABSOLUTE MAXIMUM RATING AT Ta=25°C

Parameter	Symbol	Super Bright Amber	Unit	
Power dissipation per dice	P _{AD}	70	mW	
Derating liner from 25 °C per dice	-	0.33	mA / ℃	
Continuous forward current per dice	I _{AF}	25	mA	
Peak current per dice (duty cycle 1/10, 1kHz)	I _{PF}	90	mA	
Reverse voltage per dice	V _R	5	V	
Operating temperature	T _{OPR}	-25 to +85	℃	
Storage temperature	T _{STG}	-25 to +85	∞	

ELECTRICAL - OPTICAL CHARACTERISTICS AT Ta=25°C

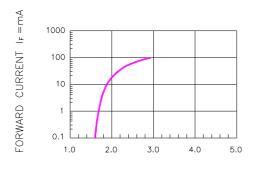
Characteristic	Symbol	Condition	Min.	Тур.	Max.	Unit
Forward voltage	V _F	I _F =20mA	-	2.0	2.6	V
Reverse current	I _R	V _R =5V	-	-	10	μA
Peak wavelength	λР	I _F =20mA	-	610	-	nm
Dominant wavelength	λ_{D}	I _F =20mA	-	606	-	nm
Luminous intensity	I _V	I _F =20mA	-	60	-	mcd
Spectral radiation bandwidth	Δλ	I _F =20mA	-	35	-	nm

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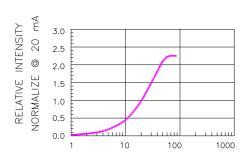


■ LA:SUPER BRIGHT AMBER (AlGaInP/GaAs) CURVE

Typical Electro-optical Characteristic Curves (25 °C Free Air Temperature Unless Otherwise Specified)



FORWARD VOLTAGE (V)
Fig.1 FORWARD CURRENT VS. FORWARD VOLTAGE



FORWARD CURRENT (mA)
Fig.2 RELATIVE INTENSITY VS. FORWARD CURRENT

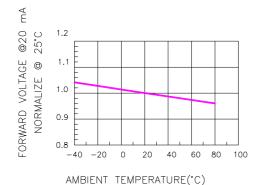


Fig.3 FORWARD VOLTAGE VS. TEMPERATURE

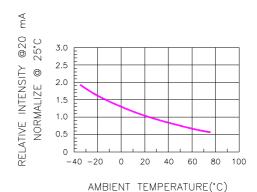


Fig.4 RELATIVE INTENSITY VS. TEMPERATURE

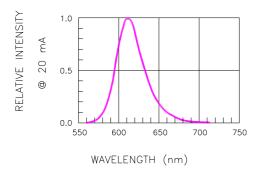
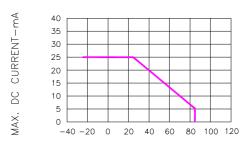


Fig.5 RELATIVE INTENSITY VS. WAVELENGTH



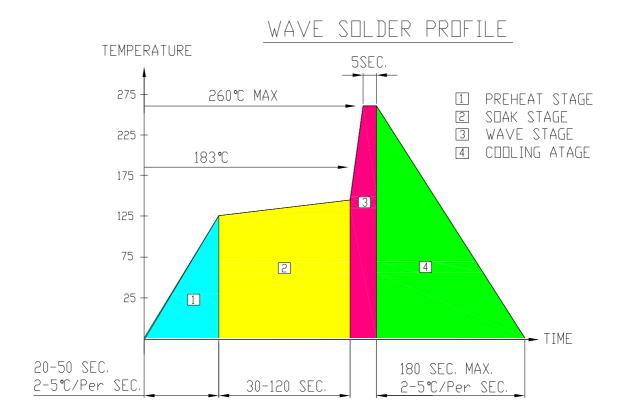
AMBIENT TEMPERATURE (TA)-°C

Fig.6 MAX. ALLOWABLE DC CURRENT VS. AMBIENT TEMPERATURE

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RECOMMEND SOLDERING PROFILE



SOLDERING IRON

Basic spec is ≦4 sec when 260°C. If temperature is higher, time should be shorter (+10°C→1 sec). Power dissipation of Iron should be smaller than 15W, and temperature should be controllable. Surface temperature of the device should be under 230°C.

REWORK

Customer must finish rework within ≤4 sec under 245°C.

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